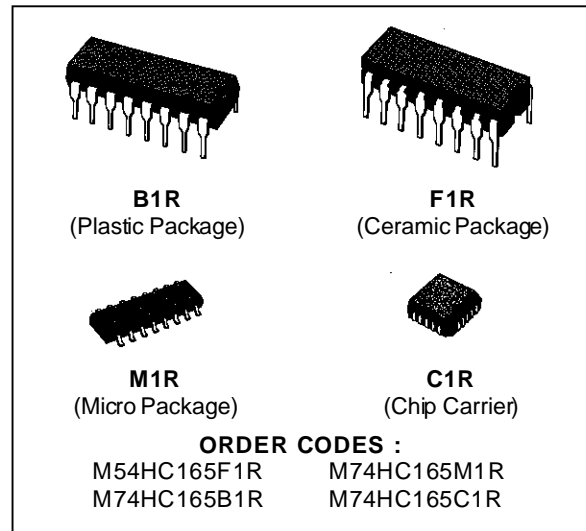


8 BIT PISO SHIFT REGISTER

- HIGH SPEED
 $t_{PD} = 15 \text{ ns (TYP.) AT } V_{CC} = 5 \text{ V}$
- LOW POWER DISSIPATION
 $I_{CC} = 4 \mu\text{A (MAX.) AT } T_A = 25 \text{ }^\circ\text{C}$
- OUTPUT DRIVE CAPABILITY
 10 LSTTL LOADS
- BALANCED PROPAGATION DELAYS
 $t_{PLH} = t_{PHL}$
- SYMMETRICAL OUTPUT IMPEDANCE
 $I_{OL} = |I_{OH}| = 4 \text{ mA (MIN.)}$
- HIGH NOISE IMMUNITY
 $V_{NIH} = V_{NIL} = 28 \% V_{CC} \text{ (MIN.)}$
- WIDE OPERATING VOLTAGE RANGE
 $V_{CC} \text{ (OPR)} = 2 \text{ V TO } 6 \text{ V}$
- PIN AND FUNCTION COMPATIBLE
 WITH 54/74LS165



DESCRIPTION

The M54/74HC165 is a high speed CMOS 8 BIT PISO SHIFT REGISTER fabricated in silicon gate C²MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption.

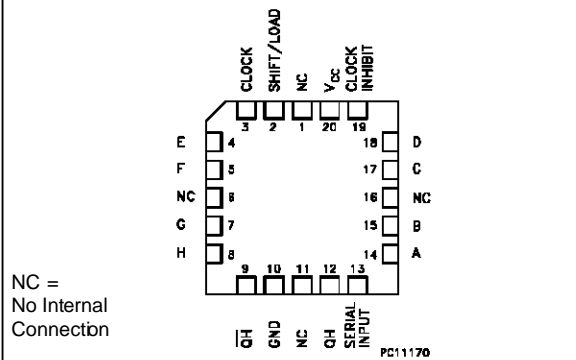
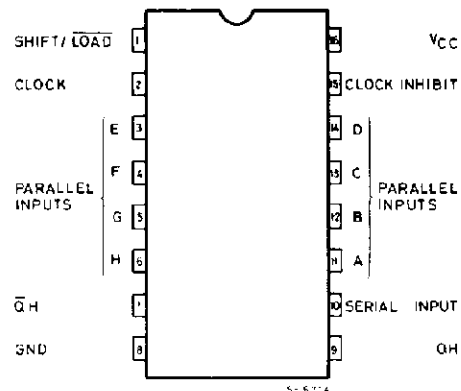
It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

This device contains eight clocked master slave RS flip-flops connected as a shift register, with auxiliary gating to provide over-riding asynchronous parallel entry. Parallel data enters when the shift/load input is low. The parallel data can change while shift/load is low, provided that the recommended set-up and hold times are observed. For clocked operation, shift/load must be high. The two clock input perform identically; one can be used as a clock inhibit by applying a high signal; to permit this operation clocking is accomplished through a 2 input nor gate.

To avoid double clocking, however, the inhibit signal should only go high while the clock is high. Otherwise the rising inhibit signal will cause the same response as rising clock edge.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

PIN CONNECTIONS (top view)



INPUT AND OUTPUT EQUIVALENT CIRCUIT



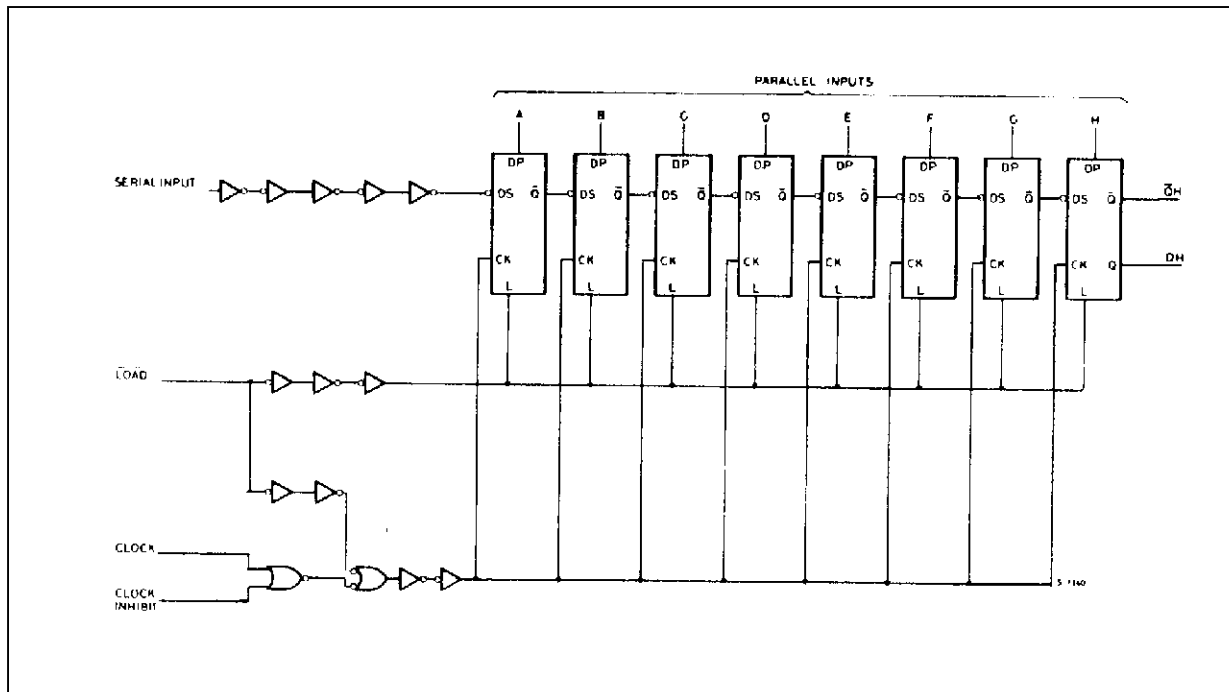
TRUTH TABLE

| INPUTS | | | | | INTERNAL OUTPUTS | | OUTPUTS |
|-----------------|------------------|-------|-----------|----------|------------------|-----|---------|
| SHIFT/ CLEAR | CLOCK INHIBIT | CLOCK | SERIAL IN | AH | QA | QB | QH |
| L | X | X | X | a.....h | a | b | h |
| H | L | | H | X | H | QAn | QGn |
| H | L | | L | X | L | QAn | QGn |
| H | | L | H | X | H | QAn | QGn |
| H | | L | L | X | L | QAn | QGn |
| H | X | H | X | X | NO CHANGE | | |
| H | H | X | X | X | NO CHANGE | | |

a.....h: The level of steady input voltage at inputs a through h respectively

QAn - QGn : The level of QA - QG, respectively, before the most-recent transition of the clock.

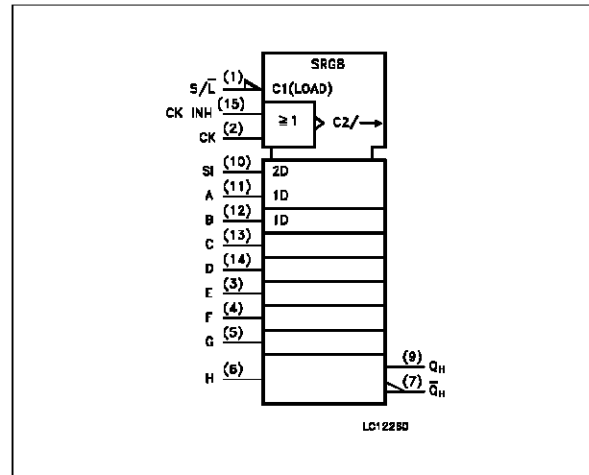
LOGIC DIAGRAM



PIN DESCRIPTION

| PIN No | SYMBOL | NAME AND FUNCTION |
|----------------------------|-----------------|--|
| 1 | S/L | Asynchronous Parallel Load Input |
| 2 | \overline{QH} | Complementary Output |
| 7 | QH | Serial Output |
| 9 | CLOCK | Clock Input (LOW to HIGH edge triggered) |
| 10 | SI | Serial Data Input |
| 11, 12, 13, 14, 3, 4, 5, 6 | A to H | Parallel Data Inputs |
| 15 | CLOCK INH | CLOCK Inhibit |
| 8 | GND | Ground (0V) |
| 16 | V _{CC} | Positive Supply Voltage |

IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-------------------------------------|--|-------------------------------|------|
| V _{CC} | Supply Voltage | -0.5 to +7 | V |
| V _I | DC Input Voltage | -0.5 to V _{CC} + 0.5 | V |
| V _O | DC Output Voltage | -0.5 to V _{CC} + 0.5 | V |
| I _{IK} | DC Input Diode Current | ± 20 | mA |
| I _{OK} | DC Output Diode Current | ± 20 | mA |
| I _O | DC Output Source Sink Current Per Output Pin | ± 25 | mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current | ± 50 | mA |
| P _D | Power Dissipation | 500 (*) | mW |
| T _{stg} | Storage Temperature | -65 to +150 | °C |
| T _L | Lead Temperature (10 sec) | 300 | °C |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.
 (*) 500 mW: ≅ 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit | |
|---------------------------------|---|---|-----------------------------------|----|
| V _{CC} | Supply Voltage | 2 to 6 | V | |
| V _I | Input Voltage | 0 to V _{CC} | V | |
| V _O | Output Voltage | 0 to V _{CC} | V | |
| T _{op} | Operating Temperature: M54HC Series M74HC Series | -55 to +125 -40 to +85 | °C °C | |
| t _r , t _f | Input Rise and Fall Time | V _{CC} = 2 V V _{CC} = 4.5 V V _{CC} = 6 V | 0 to 1000 0 to 500 0 to 400 | ns |

DC SPECIFICATIONS

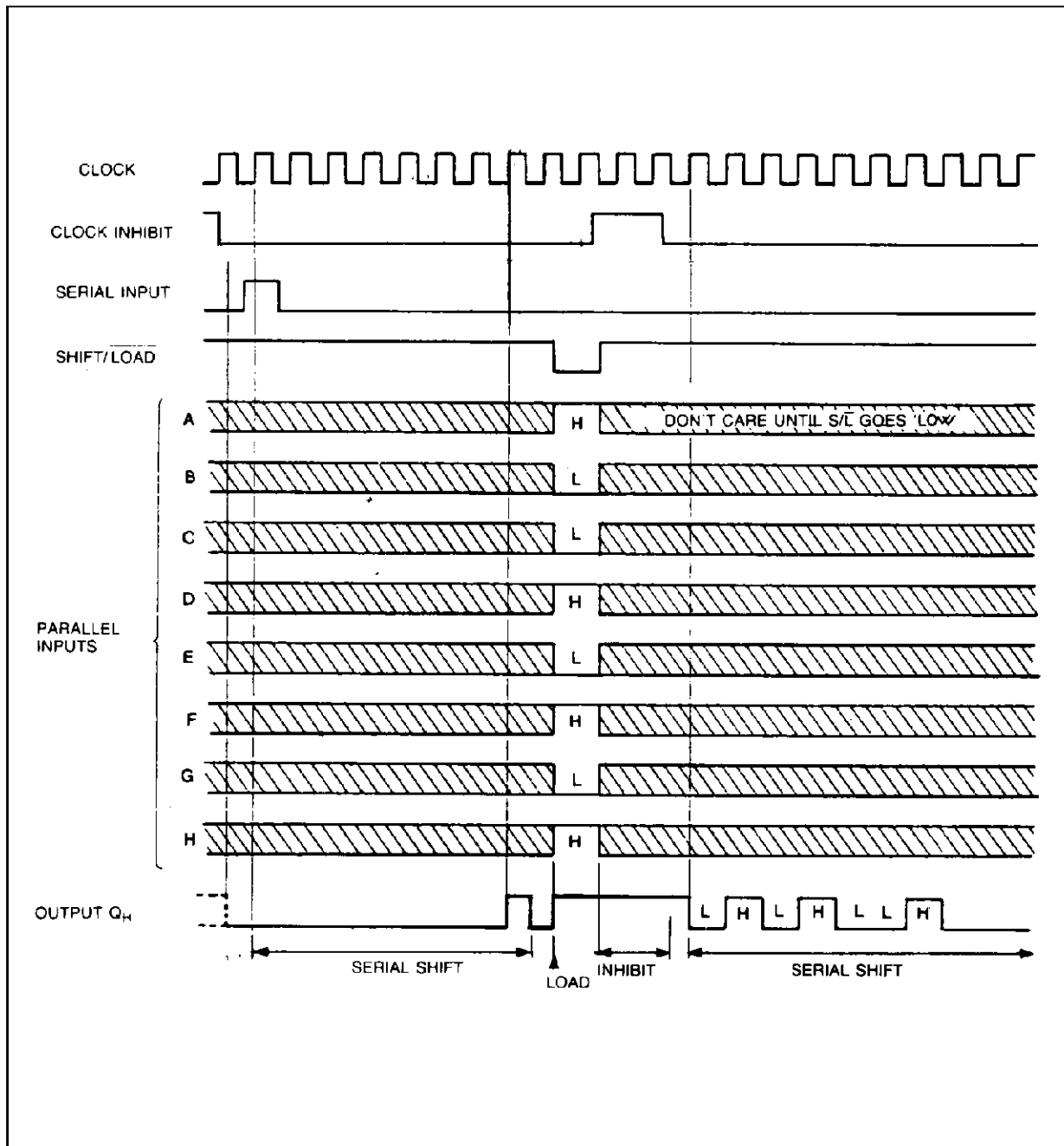
| Symbol | Parameter | Test Conditions | | Value | | | | | | Unit | | |
|-----------------|---------------------------|------------------------|--|---|-------------------------|------|----------------------|------|-----------------------|------|------|----|
| | | V _{CC} (V) | | T _A = 25 °C 54HC and 74HC | | | -40 to 85 °C 74HC | | -55 to 125 °C 54HC | | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. | |
| V _{IH} | High Level Input Voltage | 2.0 | | 1.5 | | | 1.5 | | 1.5 | | V | |
| | | 4.5 | | 3.15 | | | 3.15 | | 3.15 | | | |
| | | 6.0 | | 4.2 | | | 4.2 | | 4.2 | | | |
| V _{IL} | Low Level Input Voltage | 2.0 | | | | 0.5 | | 0.5 | | 0.5 | V | |
| | | 4.5 | | | | 1.35 | | 1.35 | | 1.35 | | |
| | | 6.0 | | | | 1.8 | | 1.8 | | 1.8 | | |
| V _{OH} | High Level Output Voltage | 2.0 | V _I = V _{IH} or V _{IL} | I _O = -20 μA | 1.9 | 2.0 | | 1.9 | | 1.9 | V | |
| | | 4.5 | | | 4.4 | 4.5 | | 4.4 | | 4.4 | | |
| | | 6.0 | | | 5.9 | 6.0 | | 5.9 | | 5.9 | | |
| | | 4.5 | I _O = -4.0 mA | 4.18 | 4.31 | | 4.13 | | 4.10 | | | |
| | | 6.0 | | I _O = -5.2 mA | 5.68 | 5.8 | | 5.63 | | 5.60 | | |
| V _{OL} | Low Level Output Voltage | 2.0 | V _I = V _{IH} or V _{IL} | I _O = 20 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | V |
| | | 4.5 | | | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | 6.0 | | | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | 4.5 | | I _O = 4.0 mA | | 0.17 | 0.26 | | 0.33 | | 0.40 | |
| | | 6.0 | | | I _O = 5.2 mA | | 0.18 | 0.26 | | 0.33 | | |
| I _I | Input Leakage Current | 6.0 | V _I = V _{CC} or GND | | | | ±0.1 | | ±1 | | ±1 | μA |
| I _{CC} | Quiescent Supply Current | 6.0 | V _I = V _{CC} or GND | | | | 4 | | 40 | | 80 | μA |

AC ELECTRICAL CHARACTERISTICS ($C_L = 50$ pF, Input $t_r = t_f = 6$ ns)

| Symbol | Parameter | Test Conditions | | Value | | | | | | Unit | |
|--|--|------------------------|--|---|------|------|----------------------|------|-----------------------|------|------|
| | | V _{CC} (V) | | T _A = 25 °C 54HC and 74HC | | | -40 to 85 °C 74HC | | -55 to 125 °C 54HC | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. |
| t _{TLH} t _{THL} | Output Transition Time | 2.0 | | | 30 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 8 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 7 | 13 | | 16 | | 19 | |
| t _{PLH} t _{PHL} | Propagation Delay Time (CK - QH, \overline{Q} H) | 2.0 | | | 55 | 150 | | 190 | | 225 | ns |
| | | 4.5 | | | 18 | 30 | | 38 | | 45 | |
| | | 6.0 | | | 15 | 26 | | 33 | | 38 | |
| t _{PLH} t _{PHL} | Propagation Delay Time (S/L - QH, \overline{Q} H) | 2.0 | | | 65 | 165 | | 205 | | 250 | ns |
| | | 4.5 | | | 21 | 33 | | 41 | | 50 | |
| | | 6.0 | | | 18 | 28 | | 35 | | 43 | |
| t _{PLH} t _{PHL} | Propagation Delay Time (H - QH, \overline{Q} H) | 2.0 | | | 52 | 135 | | 170 | | 205 | ns |
| | | 4.5 | | | 17 | 27 | | 34 | | 41 | |
| | | 6.0 | | | 14 | 23 | | 29 | | 35 | |
| f _{MAX} | Maximum Clock Frequency | 2.0 | | 7.4 | 15 | | 6.0 | | 4.8 | | MHz |
| | | 4.5 | | 37 | 60 | | 30 | | 24 | | |
| | | 6.0 | | 44 | 71 | | 35 | | 28 | | |
| t _{W(H)} t _{W(L)} | Minimum Pulse Width (CK) | 2.0 | | | 24 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 6 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 5 | 13 | | 16 | | 19 | |
| t _{W(L)} | Minimum Pulse Width (S/L) | 2.0 | | | 32 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 8 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 7 | 13 | | 16 | | 19 | |
| t _s | Minimum Set-up Time (PI - S/L) (SI - CK) (S/L - CK) | 2.0 | | | 24 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 6 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 5 | 13 | | 16 | | 19 | |
| t _h | Minimum Hold Time (S/L - PI) (CK - SI) (CK - S/L) | 2.0 | | | | 0 | | 0 | | 0 | ns |
| | | 4.5 | | | | 0 | | 0 | | 0 | |
| | | 6.0 | | | | 0 | | 0 | | 0 | |
| t _{REM} | Minimum Removal Time (CK - CKINH) | 2.0 | | | 20 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 5 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 4 | 13 | | 16 | | 19 | |
| C _{IN} | Input Capacitance | | | | 5 | 10 | | 10 | | 10 | pF |
| C _{PD} (*) | Power Dissipation Capacitance | | | | 55 | | | | | | pF |

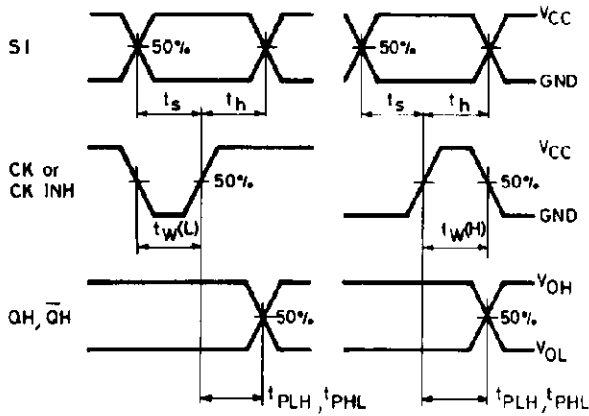
(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

TIMING CHART



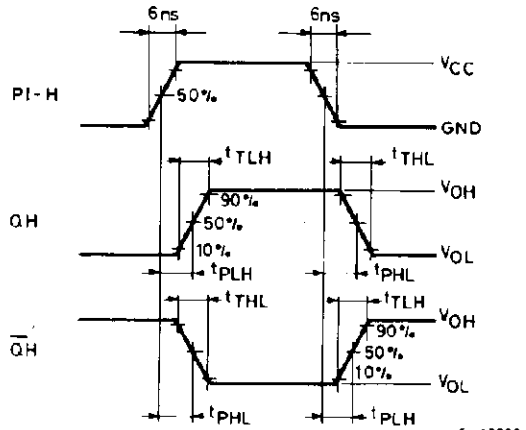
SWITCHING CHARACTERISTICS TEST WAVEFORM

SERIAL MODE



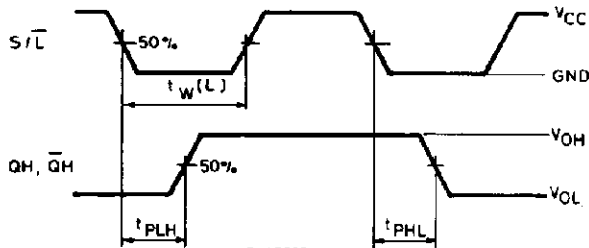
S-10327

PARALLEL MODE



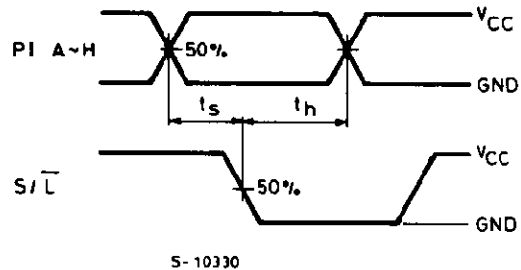
S-10328

PARALLEL MODE



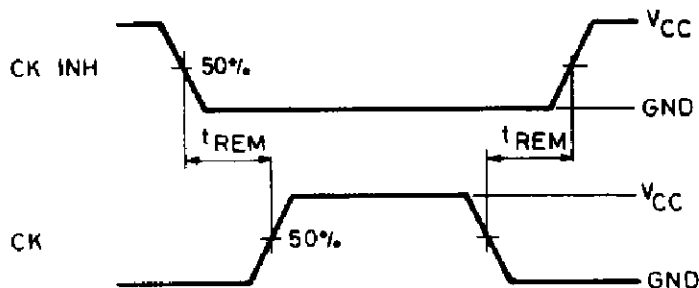
S-10329

PARALLEL MODE



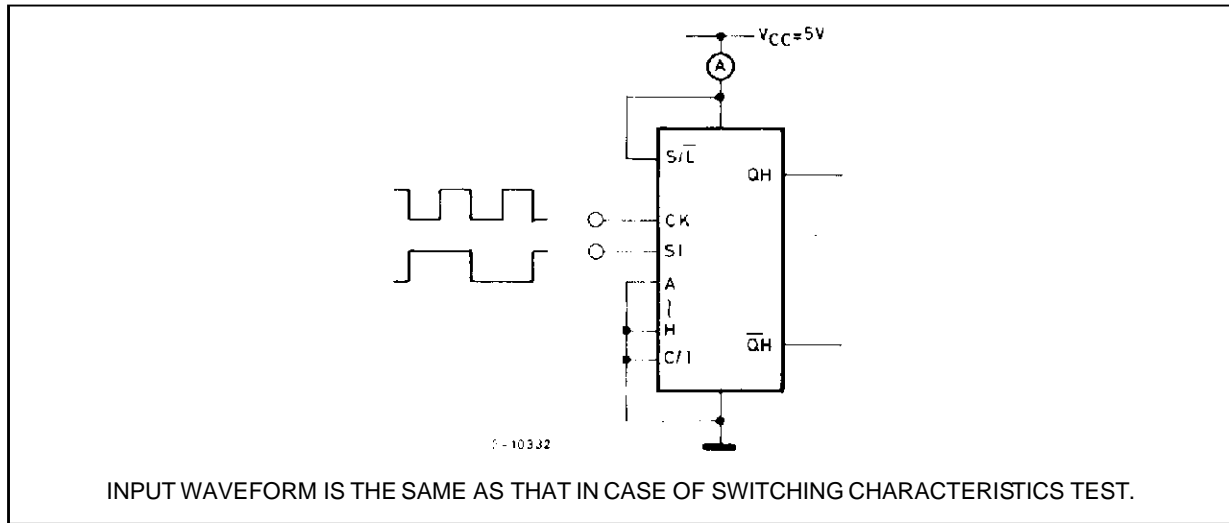
S-10330

PARALLEL MODE



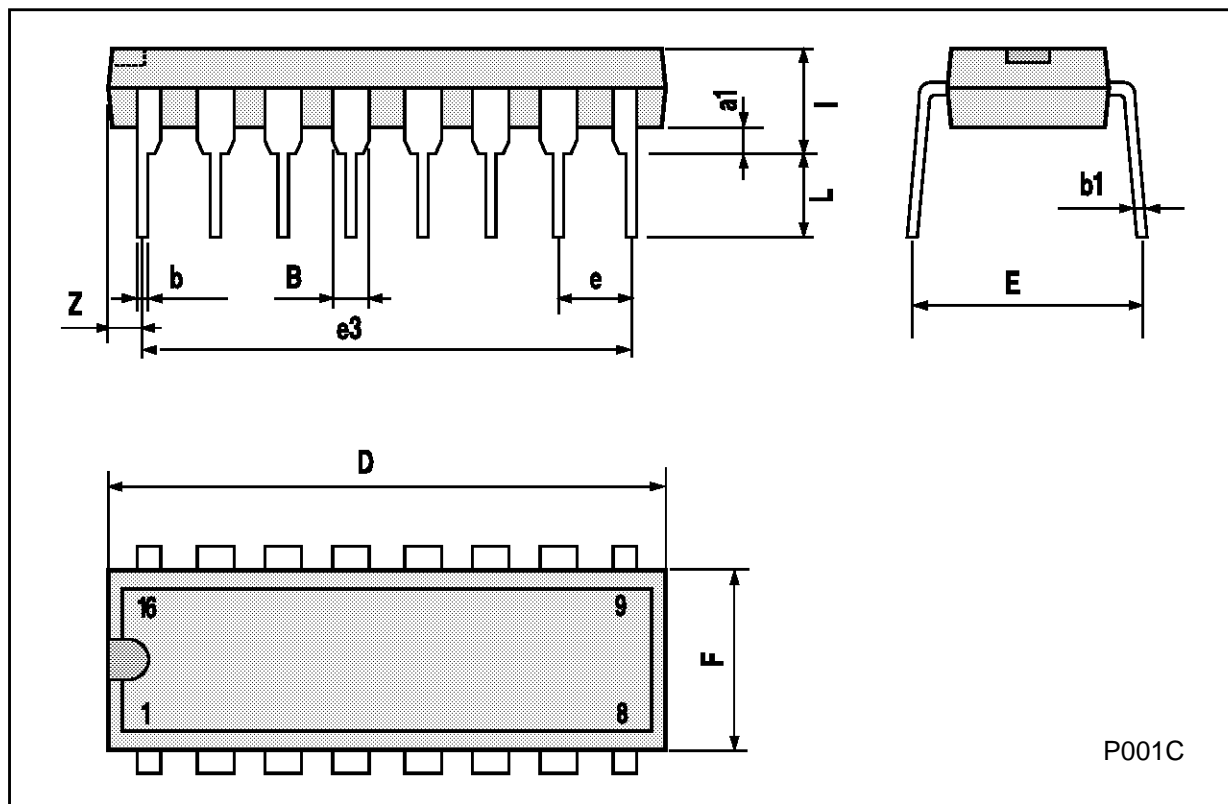
S-10331

TEST CIRCUIT I_{CC} (Opr.)



Plastic DIP16 (0.25) MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------|-------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| a1 | 0.51 | | | 0.020 | | |
| B | 0.77 | | 1.65 | 0.030 | | 0.065 |
| b | | 0.5 | | | 0.020 | |
| b1 | | 0.25 | | | 0.010 | |
| D | | | 20 | | | 0.787 |
| E | | 8.5 | | | 0.335 | |
| e | | 2.54 | | | 0.100 | |
| e3 | | 17.78 | | | 0.700 | |
| F | | | 7.1 | | | 0.280 |
| I | | | 5.1 | | | 0.201 |
| L | | 3.3 | | | 0.130 | |
| Z | | | 1.27 | | | 0.050 |



P001C

Ceramic DIP16/1 MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------|-------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 20 | | | 0.787 |
| B | | | 7 | | | 0.276 |
| D | | 3.3 | | | 0.130 | |
| E | 0.38 | | | 0.015 | | |
| e3 | | 17.78 | | | 0.700 | |
| F | 2.29 | | 2.79 | 0.090 | | 0.110 |
| G | 0.4 | | 0.55 | 0.016 | | 0.022 |
| H | 1.17 | | 1.52 | 0.046 | | 0.060 |
| L | 0.22 | | 0.31 | 0.009 | | 0.012 |
| M | 0.51 | | 1.27 | 0.020 | | 0.050 |
| N | | | 10.3 | | | 0.406 |
| P | 7.8 | | 8.05 | 0.307 | | 0.317 |
| Q | | | 5.08 | | | 0.200 |



SO16 (Narrow) MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 1.75 | | | 0.068 |
| a1 | 0.1 | | 0.2 | 0.004 | | 0.007 |
| a2 | | | 1.65 | | | 0.064 |
| b | 0.35 | | 0.46 | 0.013 | | 0.018 |
| b1 | 0.19 | | 0.25 | 0.007 | | 0.010 |
| C | | 0.5 | | | 0.019 | |
| c1 | 45° (typ.) | | | | | |
| D | 9.8 | | 10 | 0.385 | | 0.393 |
| E | 5.8 | | 6.2 | 0.228 | | 0.244 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 8.89 | | | 0.350 | |
| F | 3.8 | | 4.0 | 0.149 | | 0.157 |
| G | 4.6 | | 5.3 | 0.181 | | 0.208 |
| L | 0.5 | | 1.27 | 0.019 | | 0.050 |
| M | | | 0.62 | | | 0.024 |
| S | 8° (max.) | | | | | |



P013H

PLCC20 MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------|------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 9.78 | | 10.03 | 0.385 | | 0.395 |
| B | 8.89 | | 9.04 | 0.350 | | 0.356 |
| D | 4.2 | | 4.57 | 0.165 | | 0.180 |
| d1 | | 2.54 | | | 0.100 | |
| d2 | | 0.56 | | | 0.022 | |
| E | 7.37 | | 8.38 | 0.290 | | 0.330 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 5.08 | | | 0.200 | |
| F | | 0.38 | | | 0.015 | |
| G | | | 0.101 | | | 0.004 |
| M | | 1.27 | | | 0.050 | |
| M1 | | 1.14 | | | 0.045 | |



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